

Mounted PCA on collimating aspheric silicon substrate lens Data sheet PCA-I-g-w- λ -c

Photoconductive antenna chip

| Substrate | semi-insulating GaAs |
|-------------|----------------------|
| Chip area | 4 mm x 4 mm |
| Thickness t | 600 µm |

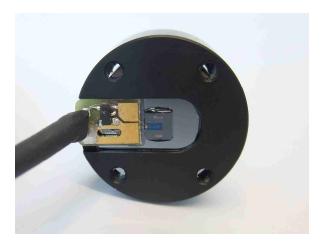
Elliptic collimating silicon lens

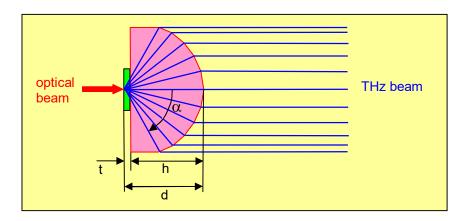
| Diameter | 20 mm |
|----------------------------|----------------------|
| Height h | 13.8 mm |
| Distance d | 14.4 mm |
| Material | undoped HRFZ-silicon |
| Specific resistance ρ | >10 kΩcm |
| Refractive index n | 3.4 |

Terahertz beam

| Beam diameter | 20 mm |
|---------------------------|-------|
| Collection angle α | 54.6° |









| Aluminum mount | 25.4 mm diameter, 6 mm thick |
|----------------|---|
| Coaxial cable | type RG 174, impedance 50 Ω , 1 m long |
| Connector type | BNC or SMA |

- The PCA chip is optically adjusted and glued on the collimating aspheric silicon lens
- The silicon lens is glued on the aluminium mount.
- The two antenna contacts are wire bonded on a printed circuit board, which provides the connection to a 1m long coaxial cable with BNC or SMA connector
- A central hole in the aluminium mount allows the Terahertz radiation to escape from the aspheric silicon lens as a collimated beam.



Complete antenna with cable and BNC connector